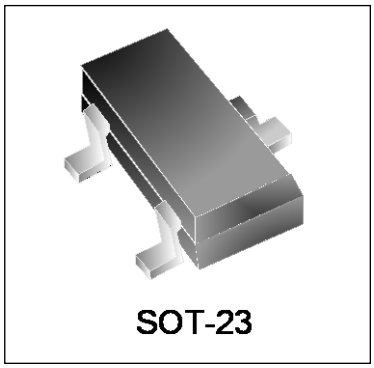
WT847C

NPN Silicon Transistor



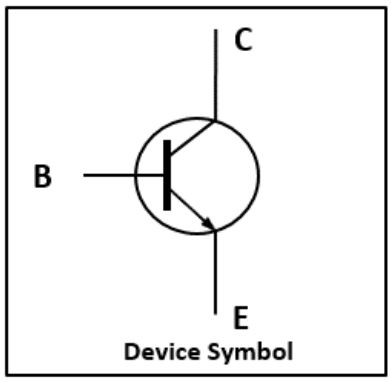
Features

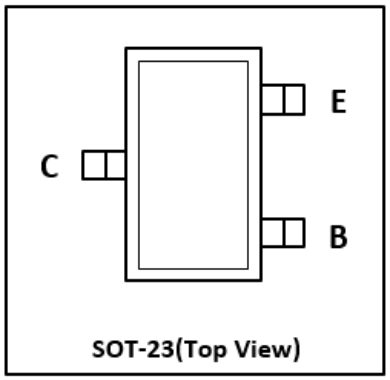
- Ideally Suited for Automatic Insertion
- For Switching and AF Amplifier Applications

Mechanical Characteristics

- SOT-23 Package
- Marking : Making Code
- RoHS Compliant

Schematic & PIN Configuration





Absolute Maximum Rating

Parameter	Symbol	Value	Unit
Collector Base Voltage	V_{CBO}	50	V
Collector Emitter Voltage	V_{CEO}	45	V
Emitter Base Voltage	V_{EBO}	6	V
Collector Current	I_C	0.1	A
Collector Power Dissipation	P_C	200	mW
Junction Temperature	T_j	150	°C
Storage Temperature	T_{stg}	-55 ~ +150	°C
Thermal Resistance from Junction to Ambient	$R_{\theta JA}$	625	°C/W

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Electrical Characteristics (T_{amb}=25°C unless otherwise noted)

Parameter	Symbol	Test Conditions	Min.	Typ.	Max.	Unit
Collector-Base Breakdown Voltage	$V_{(BR)CBO}$	I_C = 10μA, I_E = 0	50	-	-	V
Collector-Emitter Breakdown Voltage	$V_{(BR)CEO}$	I_C = 10mA, I_B = 0	45	-	-	V
Emitter-Base Breakdown Voltage	$V_{(BR)EBO}$	I_E = 10μA, I_C = 0	6	-	-	V
Collector Cut-off Current	I_{CBO}	V_{CB} = 30V, I_E = 0	-	-	15	nA
Emitter Cut-off Current	I_{EBO}	V_{EB} = 5V, I_C = 0	-	-	100	nA
DC Current Gain	h_{FE}	V_{CE} = 5V, I_C = 2mA	420	-	800	
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	I_C = 100mA, I_B = 5mA	-	-	0.4	V
Base-Emitter Saturation Voltage	$V_{BE(sat)}$	I_C = 100mA, I_B =5mA	-	-	1.1	V
Transition Frequency	f_T	V_{CE}=5V,I_C=10mA, f=100MHz	100	-	-	MHz
Collector Output Capacitance	C_{ob}	V_{CB} = 10V, f = 1MHz	-	4.5	-	pF

Typical Characteristics

Figure 1. Static Characteristics

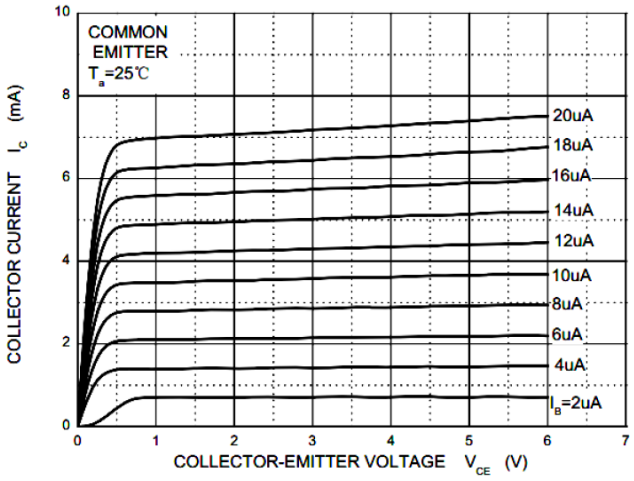


Figure 2. h_{FE} vs. I_C

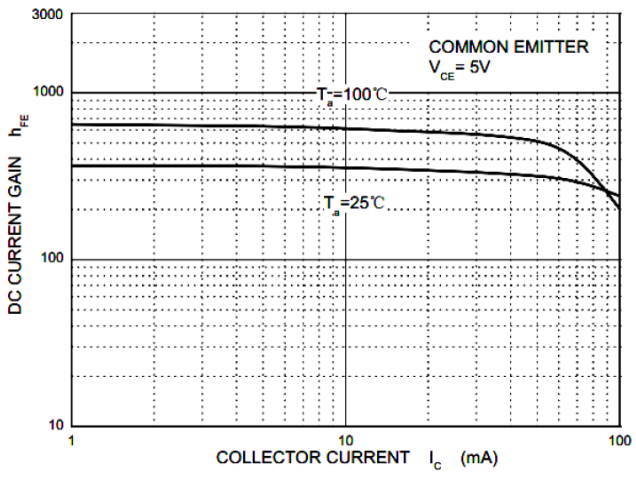


Figure 3. $V_{BE(sat)}$ vs. I_C

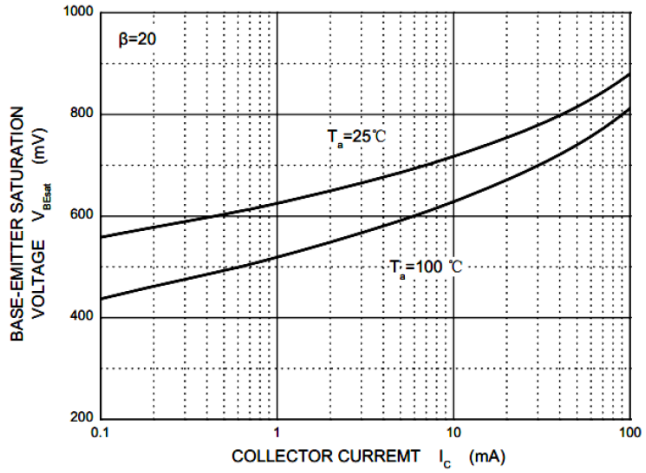


Figure 4. $V_{CE(sat)}$ vs. I_C

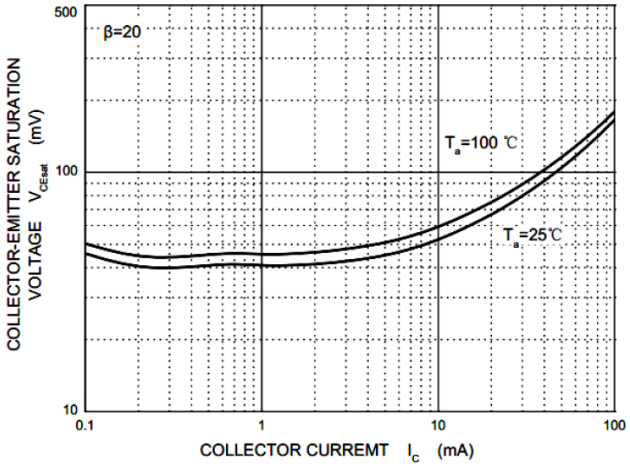


Figure 5. I_C vs. V_{BE}

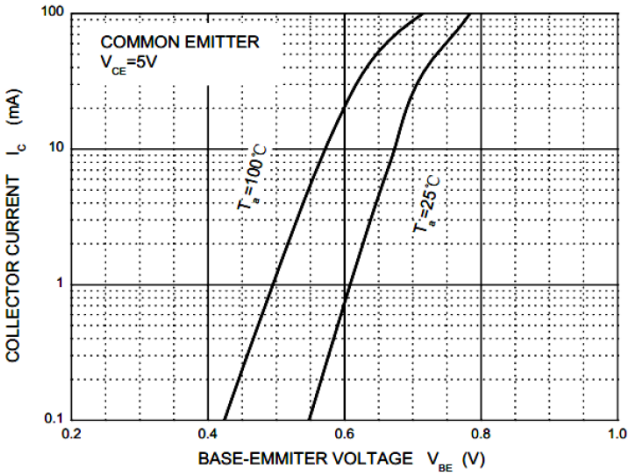


Figure 6. f_T vs. I_C

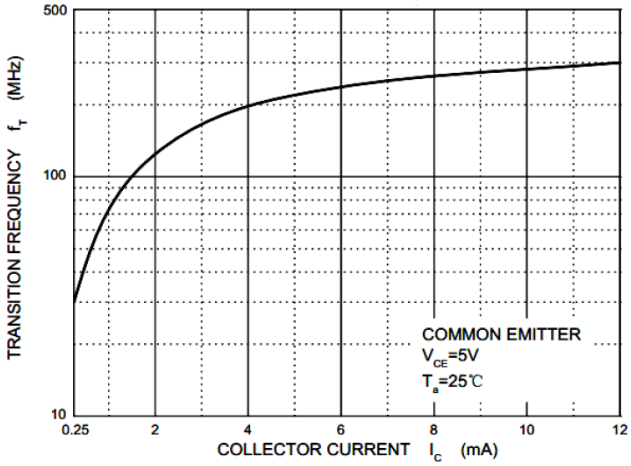


Figure 7. C_{ob} / C_{ib} vs. V_{CB} / V_{EB}

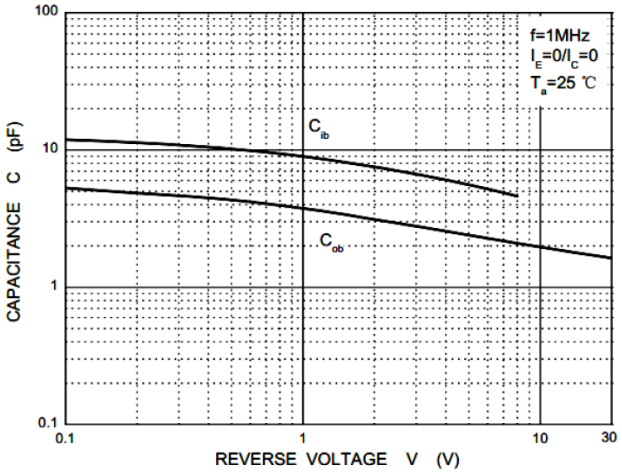
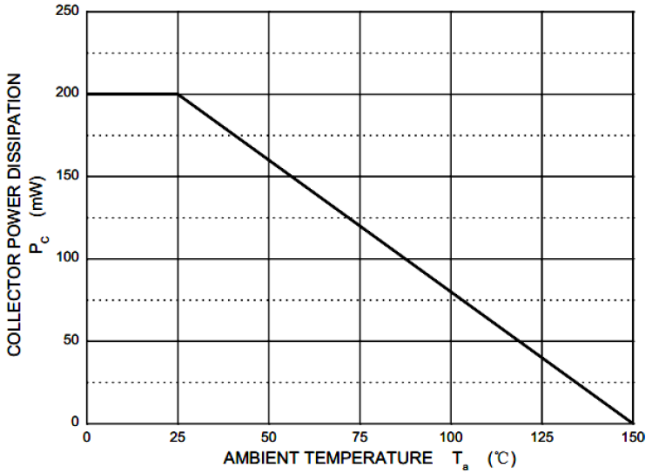
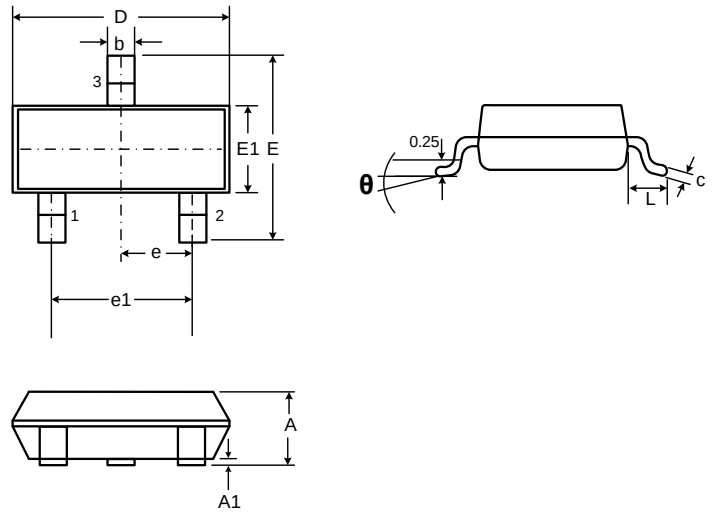


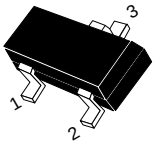
Figure 8. P_C vs. T_a



Outline Drawing – SOT-23

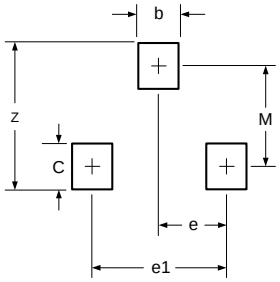
PACKAGE OUTLINE





SOT-23

DIMENSIONS				
SYMBOL	MILLIMETER		INCHES	
	MIN	MAX	MIN	MAX
A	0.90	1.15	0.035	0.045
A1	0.00	0.10	0.000	0.004
b	0.30	0.50	0.012	0.020
c	0.08	0.15	0.003	0.006
D	2.80	3.00	0.110	0.118
E	2.25	2.55	0.089	0.100
E1	1.20	1.40	0.047	0.055
e	0.95 BSC		0.0374 BSC	
e1	1.80	2.00	0.071	0.079
L	0.45	0.65	0.018	0.026
θ	0	8°	0	8°

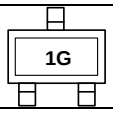


DIMENSIONS		
DIM	INCHES	MILLIMETERS
M	0.0795	2.02
C	0.0315	0.80
Z	0.111	2.82
e	0.037 BSC	0.95 BSC
e1	0.075 BSC	1.9 BSC
b	0.0315	0.80

Notes

1. Dimensioning and tolerances per ANSI Y14.5M, 1985.
2. Controlling Dimension: Inches
3. Pin 3 is the cathode (Unidirectional Only).
4. Dimensions are exclusive of mold flash and metal burrs.

Marking Codes

Part Number	WT847C
Marking Code	

Package Information

Qty：3k/Reel

CONTACT INFORMATION

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WAYON website: **http://www.way-on.com**
For additional information, please contact your local Sales Representative.

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Specifications are subject to change without notice.
The device characteristics and parameters in this data sheet can and do vary in different applications and actual device performance may vary over time.
Users should verify actual device performance in their specific applications.